

0.35-Ω Low-Voltage Dual SPDT Analog Switch

DESCRIPTION

The DG2535/DG2536 is a sub 1 Ω (0.35 Ω at 2.7 V) dual SPDT analog switches designed for low voltage applications. The DG2535/DG2536 has on-resistance matching (less than 0.05 Ω at 2.7 V) and flatness (less than 0.2 Ω at 2.7 V) that are guaranteed over the entire voltage range. Additionally, low logic thresholds make the DG2535/DG2536 an ideal interface to low voltage DSP control signals.

The DG2535/DG2536 has fast switching speed with break-before-make guaranteed. In the On condition, all switching elements conduct equally in both directions. Off-isolation and crosstalk is - 69 dB at 100 kHz.

The DG2535/DG2536 is built on Vishay Siliconix's high-density low voltage CMOS process. An epitaxial layer is built in to prevent latchup. The DG2535/DG2536 contains the additional benefit of 2,000 V ESD protection.

In space saving MSOP-10 and DFN-10 lead (Pb)-free packages, the DG2535/DG2536 are high performance, low r_{ON} switches for battery powered applications. No lead (Pb) is used in the manufacturing process either inside the device/package or on the external terminations. As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured in DFN packages, the lead (Pb)-free "-E3/E4" suffix is being used as a designator. Lead (Pb)-free DFN products purchased at any time will have either a nickel-palladium-gold device termination or a 100 % matte tin device termination. The different lead (Pb)-free materials are interchangeable and meet all JEDEC standards for reflow and MSL rating.

FEATURES

- Low Voltage Operation
- Low On-Resistance - r_{ON} : 0.35 Ω at 2.7 V
- - 69 dB OIRR at 2.7 V, 100 kHz
- MSOP-10 and DFN-10 Packages
- ESD Protection > 2000 V
- Latch-Up Current > 300 mA (JESD 78)


RoHS
COMPLIANT

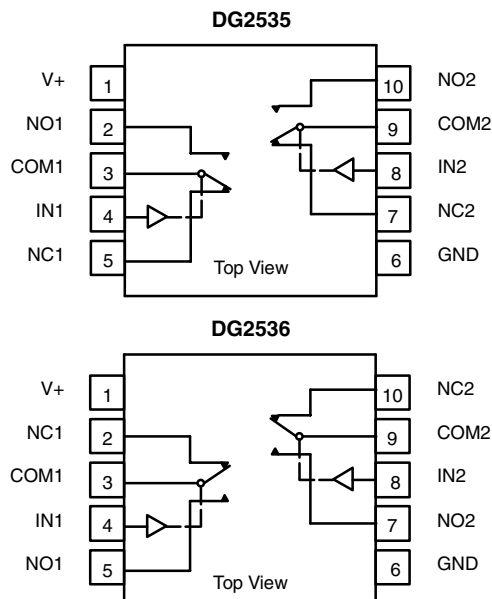
BENEFITS

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- 1.8 V Logic Compatible
- High Bandwidth

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- Battery Operated Systems
- Relay Replacement

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	NC1 and NC2	NO1 and NO2
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION

Temp Range	Package	Part Number
- 40 to 85 °C	MSOP-10	DG2535DQ-T1-E3 DG2536DQ-T1-E3
	DFN-10	DG2535DN-T1-E4 DG2536DN-T1-E4

ABSOLUTE MAXIMUM RATINGS			
Parameter		Limit	Unit
Referenced V+ to GND		- 0.3 to + 6	V
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)	
Continuous Current (NO, NC, COM)		± 300	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 500	
Storage Temperature (D Suffix)		- 65 to 150	°C
ESD per Method 3015.7		> 2	kV
Power Dissipation (Packages) ^b	MSOP-10 ^c	320	mW
	DFN-10 ^d	1191	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 4.0 mW/°C above 70 °C.

d. Derate 14.9 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS (V+ = 3 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{IN} = 0.5 or 1.4 V ^e	Temp ^a	Limits - 40 to 85 °C			Unit
				Min ^b	Typ ^c	Max ^b	
Analog Switch							
Analog Signal Range ^d	V _{NO} , V _{NC} V _{COM}	V+ = 2.7 V, V _{COM} = 0.6 V/1.5 V, I _{NO} , I _{NC} = 100 mA	Full	0		V+	V
On-Resistance	r _{ON}		Room Full		0.35	0.5 0.6	Ω
r _{ON} Flatness ^d	r _{ON} Flatness		Room		0.09	0.2	
On-Resistance Match Between Channels ^d	Δr _{DS(on)}		Room			0.05	
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	V+ = 3.3 V V _{NO} , V _{NC} = 0.3 V/3 V, V _{COM} = 3 V/0.3 V	Room Full	- 1 - 10		1 10	nA
	I _{COM(off)}		Room Full	- 1 - 10		1 10	
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3 V	Room Full	- 1 - 10		1 10	
Digital Control							
Input High Voltage ^d	V _{INH}	V _{IN} = 0 or V+	Full	1.4			V
Input Low Voltage	V _{INL}		Full			0.5	
Input Capacitance	C _{in}		Full		10		pF
Input Current	I _{INL} or I _{INH}		Full	1		1	μA



SPECIFICATIONS (V+ = 3 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, VIN = 0.4 or 2.0 V ^e	Temp ^a	Limits - 40 to 85 °C			Unit
				Min ^b	Typ ^c	Max ^b	
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 2.0 V, R _L = 50 Ω, C _L = 35 pF	Room Full		52	82 90	ns
Turn-Off Time	t _{OFF}		Room Full		43	73 78	
Break-Before-Make Time	t _d		Full	1	6		
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{GEN} = 1.5 V, R _{GEN} = 0 Ω	Room		21		pC
Off-Isolation ^d	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 100 kHz	Room		- 69		dB
Crosstalk ^d	X _{TALK}		Room		- 69		
N _O , N _C Off Capacitance ^d	C _{NO(off)}	VIN = 0 or V+, f = 1 MHz	Room		145		pF
	C _{NC(off)}		Room		145		
Channel-On Capacitance ^d	C _{NO(on)}	VIN = 0 or V+, f = 1 MHz	Room		406		
	C _{NC(on)}		Room		406		
Power Supply							
Power Supply Current	I+	VIN = 0 or V+	Full			1.0	μA

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

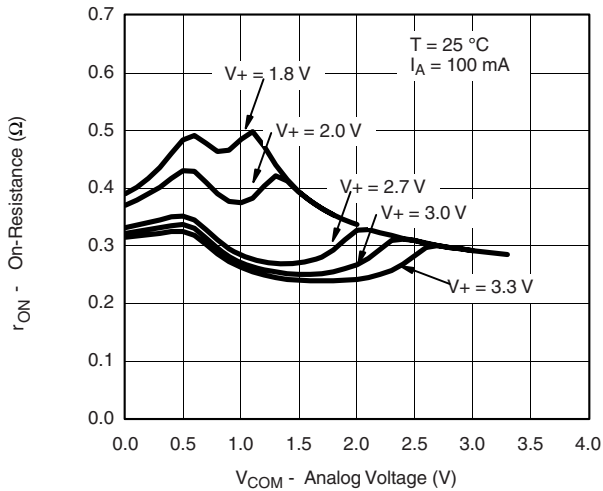
b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

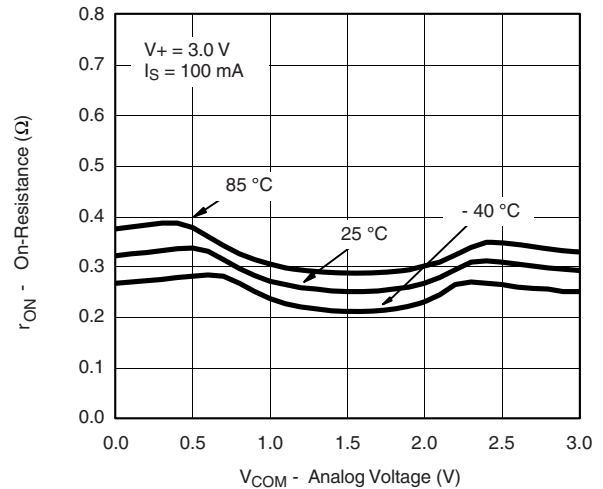
d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

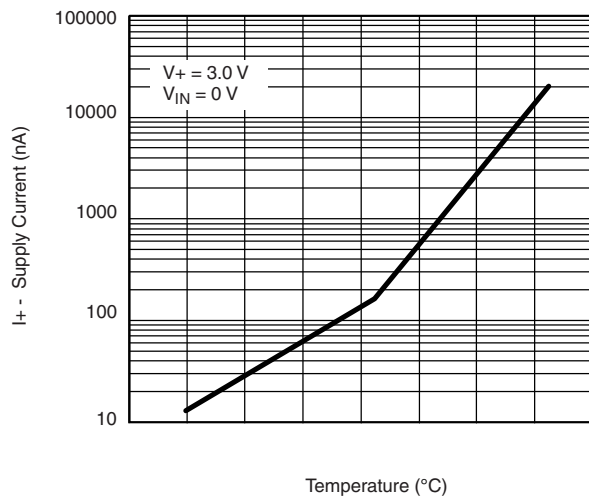
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



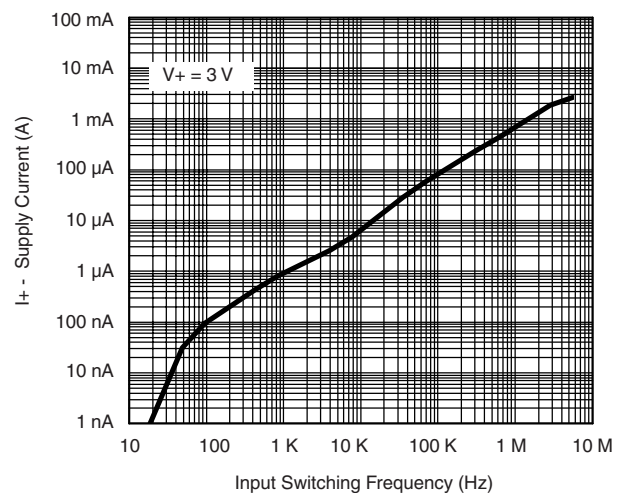
r_{ON} vs. V_{COM} and Supply Voltage



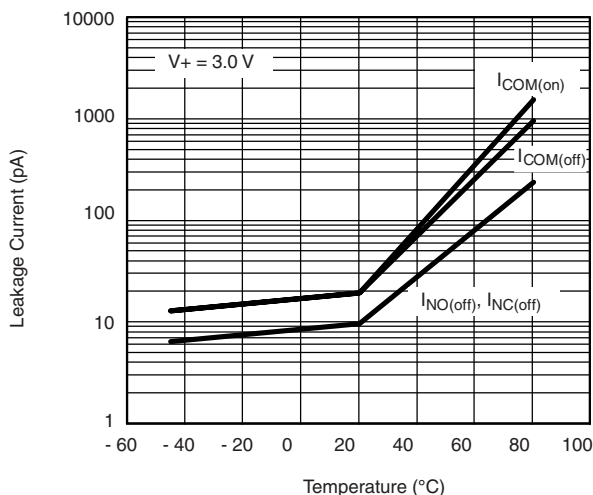
r_{ON} vs. Analog Voltage and Temperature (NC1)



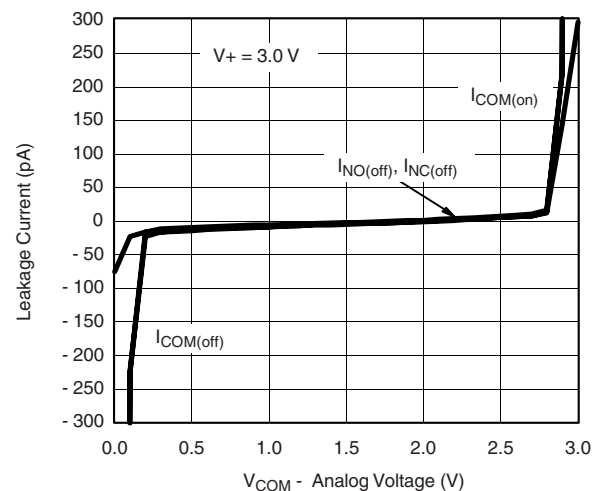
Supply Current vs. Temperature



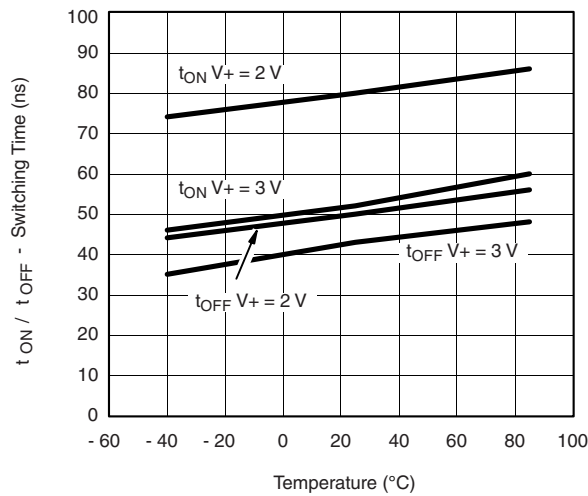
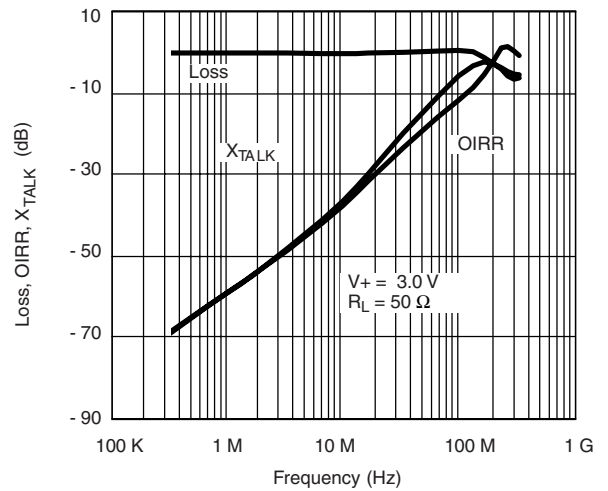
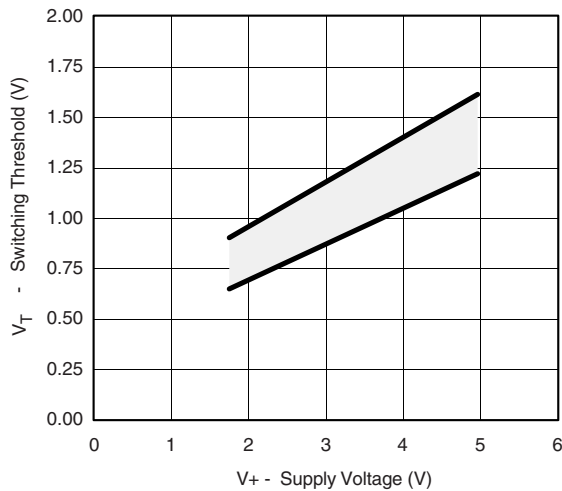
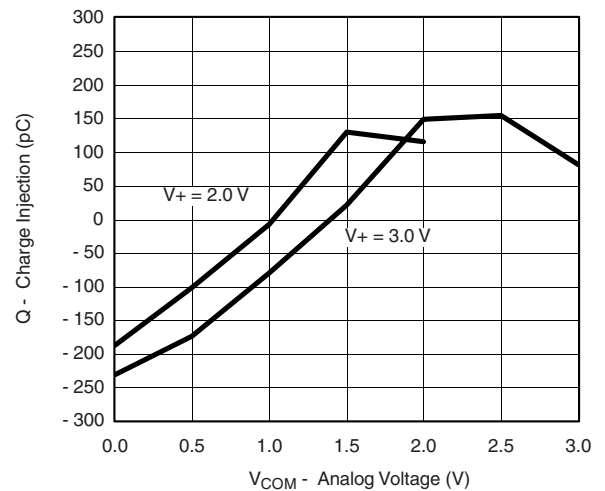
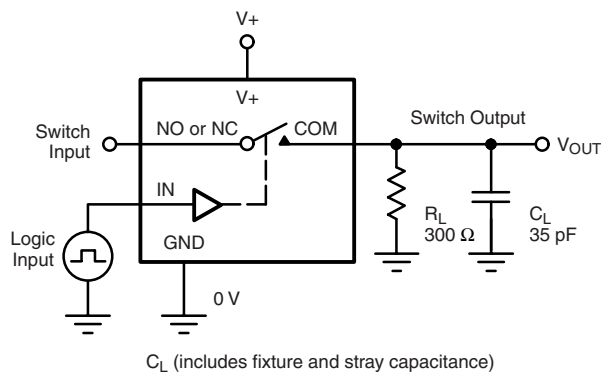
Supply Current vs. Input Switching Frequency



Leakage Current vs. Temperature

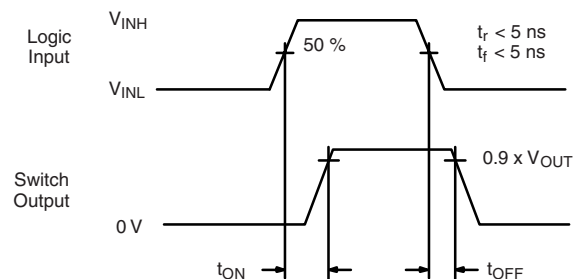


Leakage vs. Analog Voltage

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Switching Time vs. Temperature

Insertion Loss, Off-Isolation Crosstalk vs. Frequency

Switching Threshold vs. Supply Voltage

Charge Injection vs. Analog Voltage
TEST CIRCUITS


C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

TEST CIRCUITS

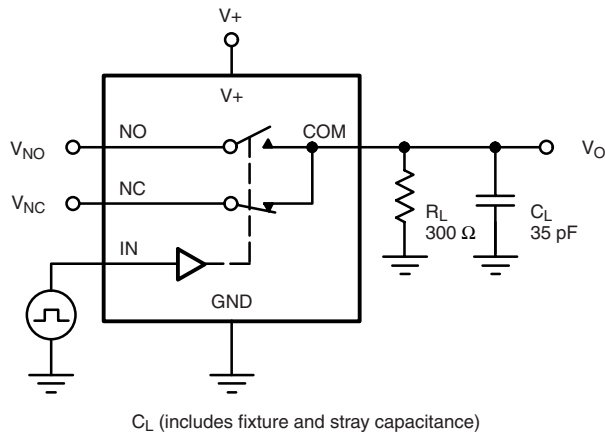


Figure 2. Break-Before-Make Interval

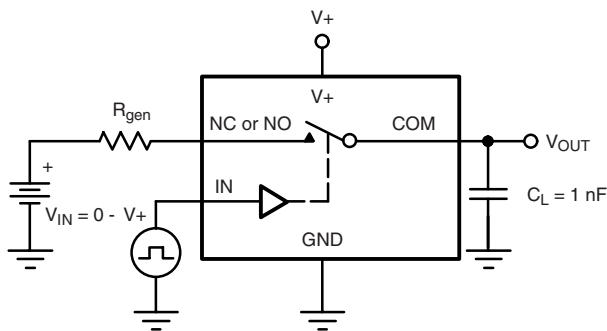
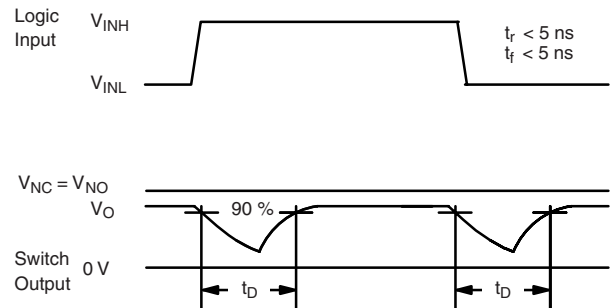


Figure 3. Charge Injection

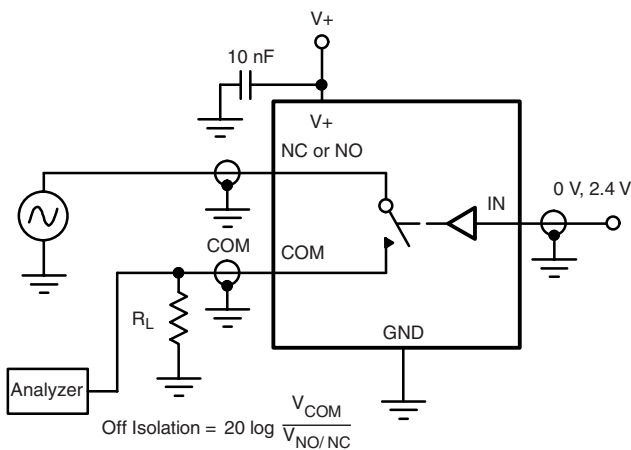
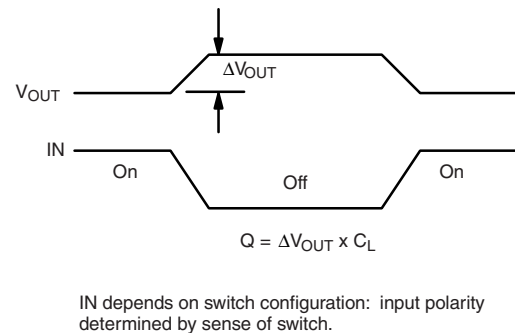


Figure 4. Off-Isolation

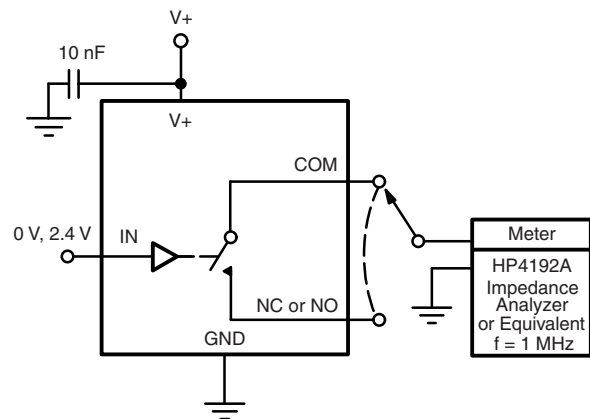


Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?72939>.



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9